

TECHNICAL DATA DATASHEET 4726, REV. B

# HERMETIC POWER SCHOTTKY RECTIFIER 175°C Maximum Operation Temperature

**DESCRIPTION:** A 60-VOLT, 30/35 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC TO-254 PACKAGE.

## **MAXIMUM RATINGS**

ALL RATINGS ARE @  $T_C$  = 25 °C UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	60	Volts
MAXIMUM DC OUTPUT CURRENT (@ T <sub>C</sub> =100 <sup>O</sup> C) (Single, Doubler)	Io	30	Amps
MAXIMUM DC OUTPUT CURRENT (@ T <sub>C</sub> =100 <sup>O</sup> C) (Common Cathode, Common Anode)	Io	35	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t=8.3ms, Sine)	I <sub>FSM</sub>	570	Amps
MAXIMUM JUNCTION CAPACITANCE (V <sub>r</sub> =5V)	C <sub>T</sub>	1600	pF
MAXIMUM THERMAL RESISTANCE (Per leg)	$R_{ ext{ hetaJC}}$	1.5	°C/W
MAXIMUM OPERATING TEMPERATURE RANGE	Top/Tstg	-65 to + 175	°C
MAXIMUM STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 175	°C

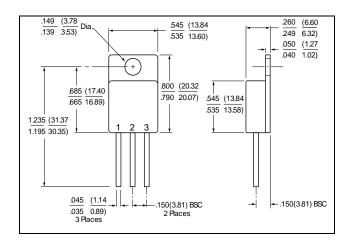
## **ELECTRICAL CHARACTERISTICS**

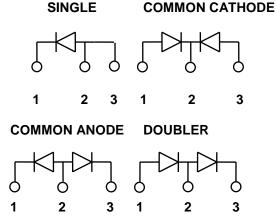
CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I <sub>f</sub> = 30 Amps)			
T <sub>J</sub> = 25 °C	$V_{f}$	0.91	Volts
T <sub>J</sub> = 125 °C		0.84	
MAXIMUM REVERSE CURRENT (I <sub>r</sub> @ 60 V PIV)			
T <sub>J</sub> = 25 °C	I <sub>r</sub>	0.8	mA
T <sub>J</sub> = 125 °C		60	

## **SENSITRON**

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## Mechanical Dimensions: In inches / mm





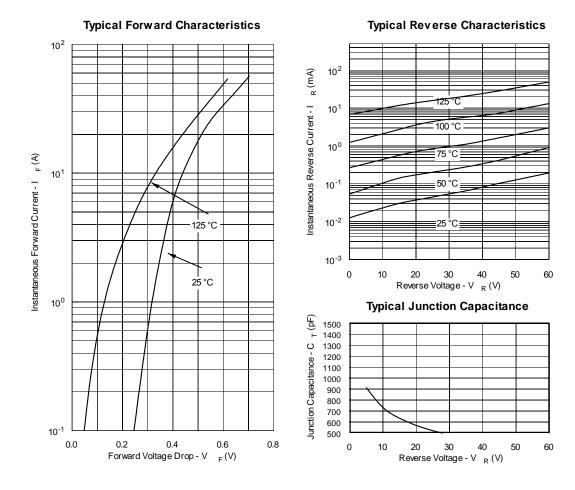
# **TO-254**

## **PINOUT TABLE**

TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
DUAL RECTIFIER, COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER, COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DUAL RECTIFIER, DOUBLER (D)	ANODE	CATHODE/ ANODE	CATHODE

## **SENSITRON**

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